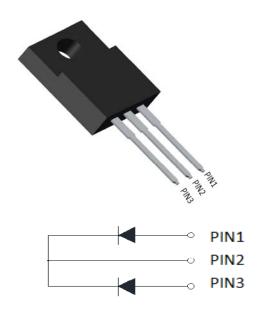


# **Ultra-Fast Recovery Rectifier Diodes**



#### **Features**

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Adopt GPP chip
- Passivation for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

## **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

• Package: ITO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

## ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1640FCT-B1-0000S	MUR1660FCT-B1-0000S
Device marking code			MUR1640FCT	MUR1660FCT
Repetitive Peak Reverse Voltage	VRRM	V	400	600
Average Rectified Output Current @60Hz half sine-wave, R-load, Tc(FIG.1)	lo	Α	16	
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T <sub>a</sub> =25°C	IFSM	Α	100	
Current Squared Time @1ms≤t≤8.3ms Tj=25°C, Rating of per diode	l <sup>2</sup> t	A <sup>2</sup> s	41	
Storage Temperature	T <sub>stg</sub>	$^{\circ}$	-55 ~ +150	
Junction Temperature	Tj	$^{\circ}$	-55 ~ <b>+</b> 150	

## **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MUR1640FCT-B1-0000S	MUR1660FCT-B1-0000S
Maximum instantaneous forward voltage drop per diode	VFM	٧	IFM=8.0A	1.3	1.5
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1		VRM=VRRM T <sub>a</sub> =25℃	10	
	IRRM2	uA	VRM=VRRM T <sub>a</sub> =125℃	500	
Reverse Recovery Time	Trr	ns	I <sub>F</sub> =0.5A I <sub>RM</sub> =1A I <sub>RR</sub> =0.25A	50	

## **■Thermal Characteristics** $(T_a=25$ $^{\circ}$ C Unless otherwise specified)

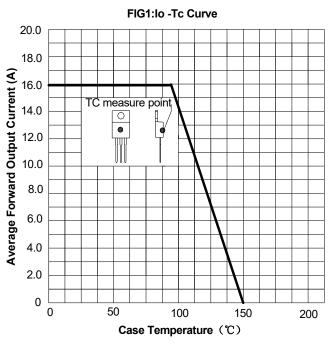
P.A	RAMETER	SYMBOL	UNIT	MUR1640FCT	MUR1660FCT
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	°C/W	2	5

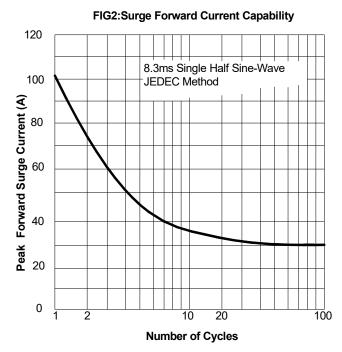


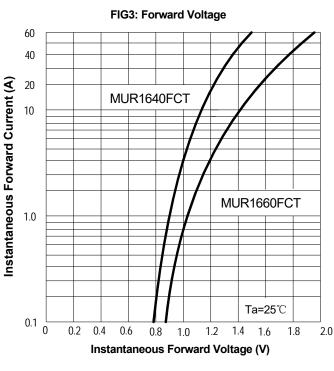
**■Ordering Information** (Example)

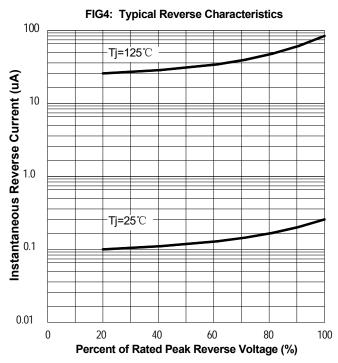
PREFER	RED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1640FCT-B1- 0000S	MUR1660FCT-B1- 0000S	Approximate 1.47	50	1000	5000	Tube

## **■Characteristics** (Typical)











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NONINDUCTIVE

DUT

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PULSE
GENERATOR
(NOTE2)

10

NONINDUCTIVE

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NONINDUCTIVE

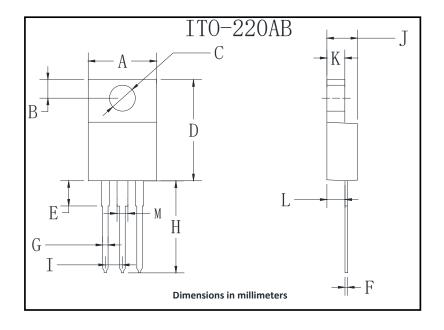
NOTES:
1.Rise Time=7ns max .Inpot Impedance=IM \( \Omega \) 22pf
2.Rise Time=10ns max.Sourse Impedance=50 \( \Omega \)

1cm

SET TIME BASE FOR 5/10ns/cm

FIG.5 Diagram of circuit and Testing wave form of reverse recovery time

## **■**Outline Dimensions



ITO-220AB				
Dim	Min	Max		
Α	9.7	10.7		
В	2.15	3.25		
С	2.6	3.8		
D	14.4	15.9		
E	3.1	4.5		
F	0.4	0.8		
G	0.4	0.8		
Н	12.7	14.2		
1	1.80	2.95		
J	3.9	5.1		
K	2.1	3.56		
L	2.1	3.2		
М	1.4	1.8		



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